MH203A

High Linearity Cellular-Band MMIC Mixer

The Communications Edge ™

Product Information

Product Features

- +34 dBm Input IP3
- 7.3 dB Conversion Loss
- RF: 800 – 960 MHz
- LO: 1000 – 1310 MHz
- IF: 70 – 350 MHz
- +17 dBm Drive Level
- Lead-free / RoHS-compliant / Green SOIC-8 package
- No External Bias Required

Applications

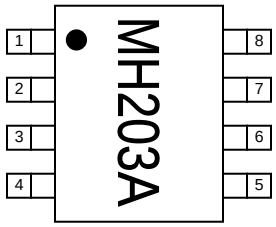
- 2.5G and 3G GSM/CDMA/ wCDMA Mobile Infrastructure

Product Description

The MH203A is a passive GaAs MESFET mixer that provides high dynamic range performance in a low-cost lead-free/green/RoHS-compliant SOIC-8 package. WJ's MH203A uses patented techniques to realize +34 dBm Input IP3 at an LO drive level of +17 dBm and can be used for upconverting or downconverting high-side LO applications. This single monolithic integrated circuit does not require any external baluns or bias elements.

Typical applications include frequency up/down conversion, modulation and demodulation for receivers and transmitters used in 2.5G and 3G GSM/CDMA/wCDMA mobile infrastructure in the cellular frequency band.

Functional Diagram



Function	Pin No.
LO	2
IF & RF*	7
GND	1, 3, 4, 6, 8
N/C or GND	5

* External components (inductors & capacitors) are required to diplex the signal

Specifications

Parameters	Units	Min	Typ	Max	Comments
RF Frequency Range	MHz		800 – 960		
LO Frequency Range	MHz		1000 – 1310		
IF Frequency Range	MHz		70 – 350		
SSB Conversion Loss	dB		7.3	8.5	See note 1
Noise Figure	dB		7.8	9.0	See note 2
Input IP3	dBm	+28	+31.5		RF=900-960MHz, IF>300MHz, See note 3
Input IP3	dBm	+30	+34		All other RF/IF combinations, See notes 1 and 3
Input P1dB	dBm		+17.5		
2*LO – RF Isolation	dB		35		Referenced to the LO level at the RF port
LO – RF Isolation	dB	25	30		
LO – IF Isolation	dB	50	60		
RF – IF Isolation	dB		25		
Return Loss: RF Port	dB	10	20		See note 4
Return Loss: IF Port	dB	10	23		See note 4
Return Loss: LO Port	dB	10	15		LO=1064-1089MHz, See note 5
LO Drive Level	dBm		+17		

1. Test conditions unless otherwise noted: RF / IF = 803 / 200, 963 / 200, and 963 / 350 MHz with a high-side LO at +17 dBm in a downconverting application at 25 °C. The diplexer shown on the application circuit is used in the test fixture.
2. Assumes LO injection noise is filtered at the thermal noise floor, -174 dBm/Hz, at the RF, IF, and Image frequencies.
3. IIP3 is measured with Δf = 1 MHz with RFin = 0 dBm / tone.
4. The return loss is measured after the diplexer which splits the RF and IF signals from the mixer.
5. The minimum LO port return loss is 9 dB for LO=1000-1064MHz and LO=1089-1310MHz.

Absolute Maximum Rating

Parameter	Rating
Operating Case Temperature	-40 to +85 °C
Storage Temperature	-65 to +100 °C
LO Power	+21 dBm
Input IF / RF Power	+20 dBm

Operation of this device above any of these parameters may cause permanent damage.

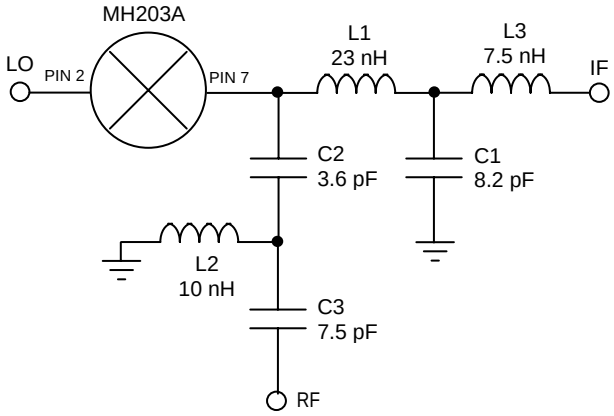
Ordering Information

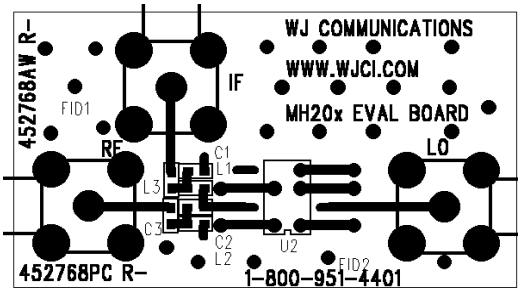
Part No.	Description
MH203A-G	High Dynamic Range Cellular-band MMIC Mixer (lead-free/green/RoHS-compliant SOIC-8 package)
MH203A-PCB	Fully-Assembled Mixer Application Board

Specifications and information are subject to change without notice

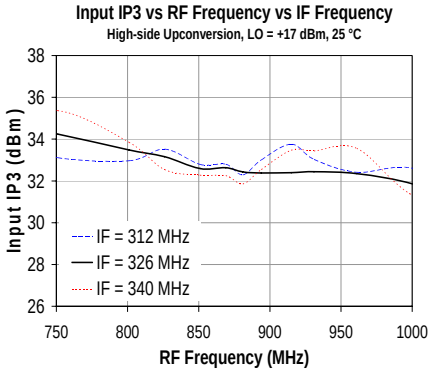
Typical Upconversion Performance Plots

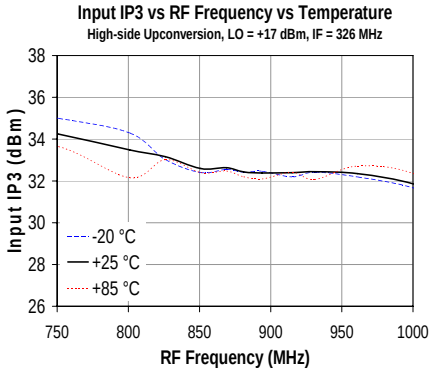
Performance using the circuitry on the MH203A-PCB Evaluation Board

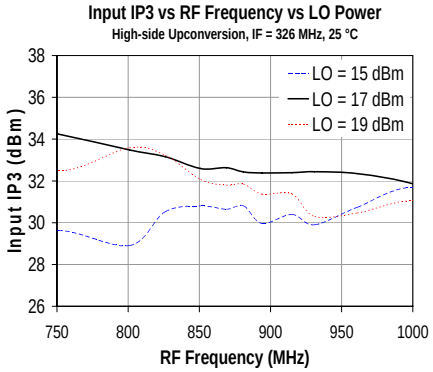


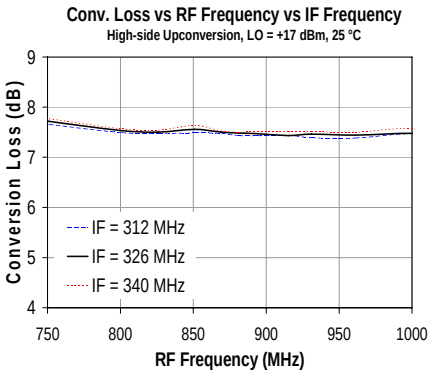


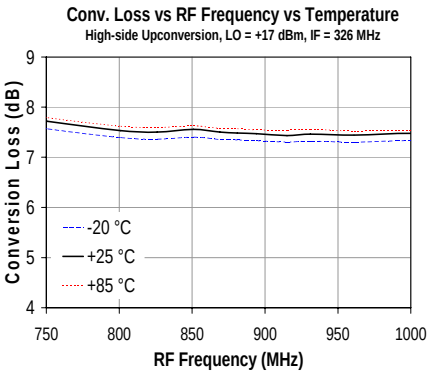
Circuit Board Material: .014" FR-4, 4 layers, .062" total thickness
All passive components are 0402 size.
All other pins on mixer are grounded.

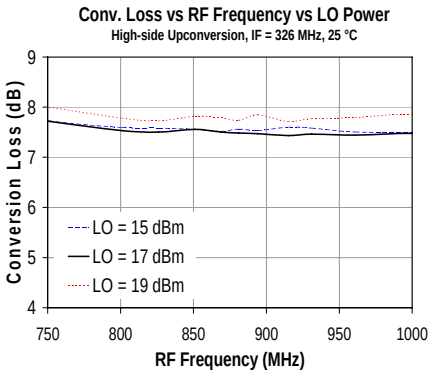


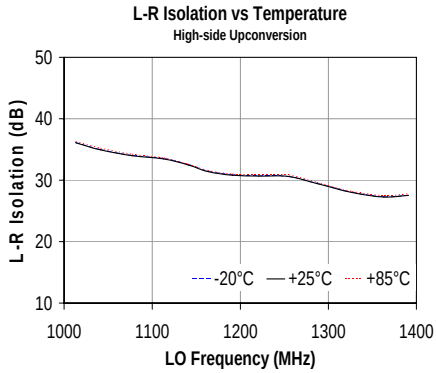


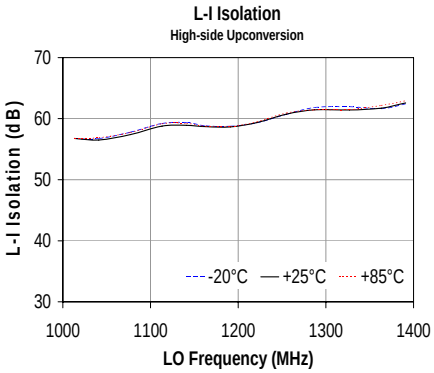








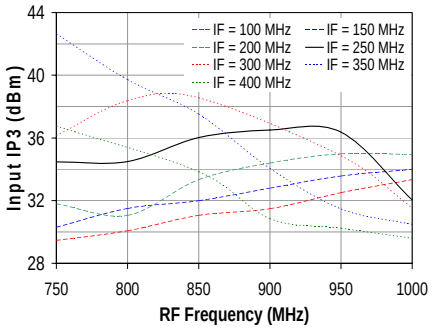




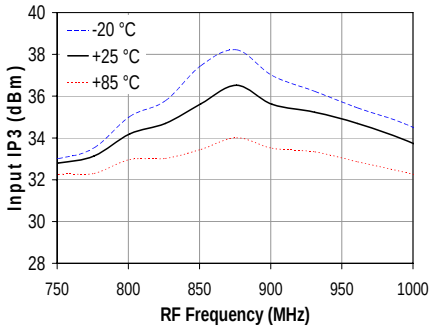
Typical Downconversion Performance Plots

Performance using the circuitry on the MH203A-PCB Evaluation Board

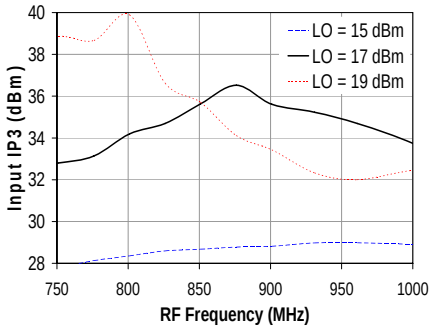
Input IP3 vs RF Frequency
High-side Downconversion, LO = +17 dBm, 25 °C



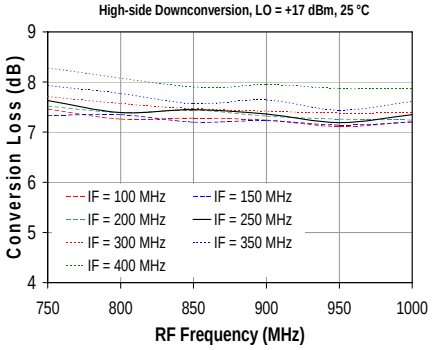
Input IP3 vs RF Frequency vs Temperature
High-side Downconversion, LO = +17 dBm, IF = 240 MHz



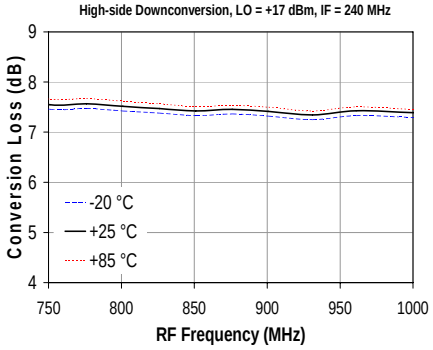
Input IP3 vs RF Frequency vs LO Power
High-side Downconversion, IF = 240 MHz, 25 °C



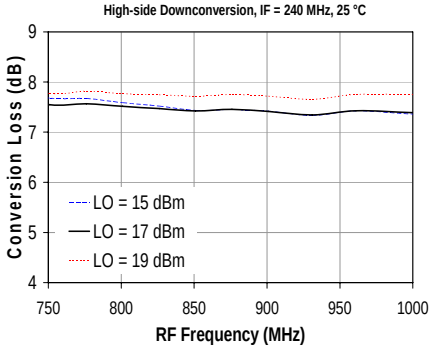
Conversion Loss vs RF Frequency
High-side Downconversion, LO = +17 dBm, 25 °C



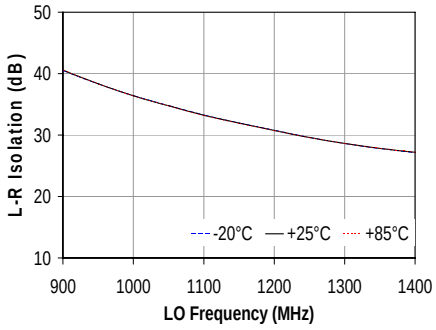
Conv. Loss vs RF Frequency vs Temperature
High-side Downconversion, LO = +17 dBm, IF = 240 MHz



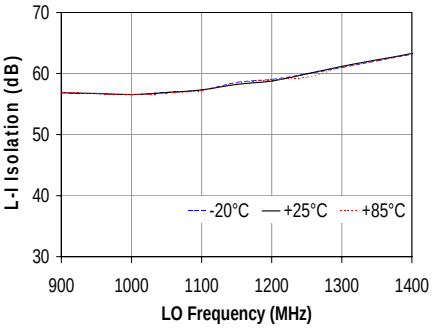
Conv. Loss vs RF Frequency vs LO Power
High-side Downconversion, IF = 240 MHz, 25 °C



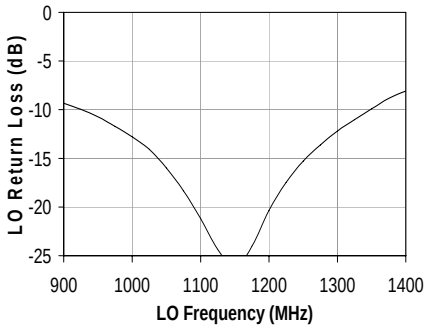
L-R Isolation vs Temperature
High-side Downconversion



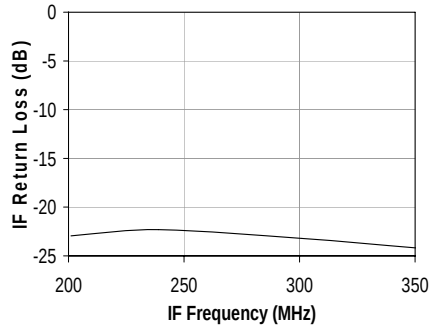
L-I Isolation
High-side Downconversion



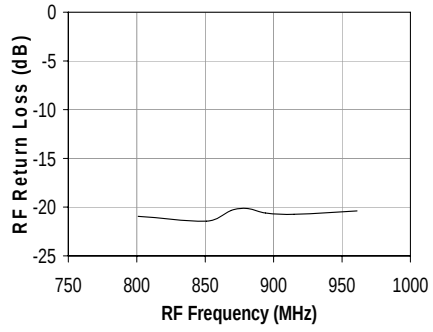
LO Return Loss
LO = +17 dBm, 25 °C



IF Return Loss
LO = +17 dBm, 25 °C



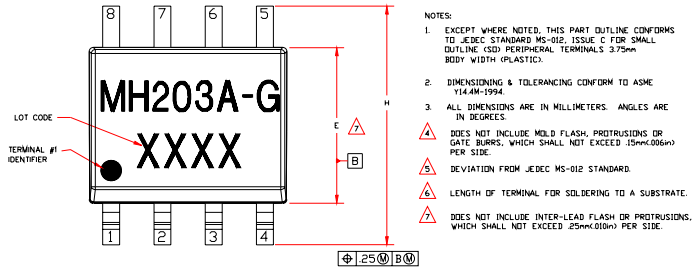
RF Return Loss
LO = +17 dBm, 25 °C



MH203A-G (Lead-Free/Green SOIC-8 Package) Mechanical Information

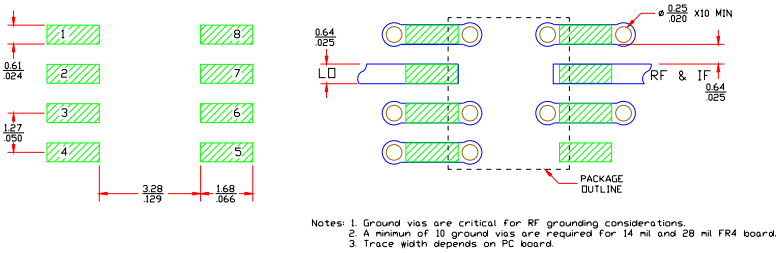
This package is lead-free/green/RoHS-compliant. The plating material on the leads is NiPdAu. It is compatible with both lead-free (maximum 260 °C reflow temperature) and lead (maximum 245 °C reflow temperature) soldering processes.

Outline Drawing



SYMBOL	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
A	1.30	1.40	.051	.055
A1	.10	.25	.004	.010
b	.41		.016	
C	.20		.008	
D	4.80	5.00	.189	.197
E	3.80	4.00	.150	.157
e	1.27 BSC		.050 BSC	
H	5.80	6.20	.228	.244
h	.25	.50	.01	.02
L	.40	1.27	.016	.050
t	0	8°	0	8°

Land Pattern / Mounting Configuration



Product Marking

The component will be marked with an "MH203A-G" designator with an alphanumeric lot code on the top surface of the package. The obsolete tin-lead package is marked with an "M203A" designator with an alpha numeric lot code.

Tape and reel specifications for this part are located on the website in the "Application Notes" section.

ESD / MSL Information

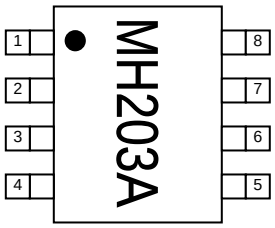
Caution! ESD sensitive device.

ESD Rating: Class 1B
Value: Passes ≥500V to <1000 V
Test: Human Body Model (HBM)
Standard: JEDEC Standard JESD22-A114

ESD Rating: Class III
Value: Passes ≥500 V to <1000 V
Test: Charged Device Model (CDM)
Standard: JEDEC Standard JESD22-C101

MSL Rating: Level 2 at +260 °C convection reflow
Standard: JEDEC Standard J-STD-020

Functional Pin Layout



Pin	Function
1	Ground
2	LO Port
3	Ground
4	Ground
5	No Connect / Ground
6	Ground
7	RF / IF Port*
8	Ground

* External components (inductors & capacitors) are required to diplex the signal